### SN54LVC373A, SN74LVC373A OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

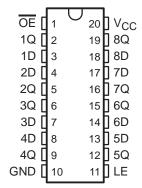
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- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   < 0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
   2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Power Off Disables Outputs, Permitting Live Insertion
- Support Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V<sub>CC</sub>)
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), Ceramic Flat (W) Packages, and DIPs (J)

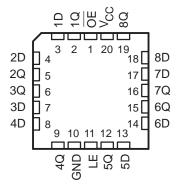
#### description

The SN54LVC373A octal transparent D-type latch is designed for 2.7-V to 3.6-V  $V_{CC}$  operation and the SN74LVC373A octal transparent D-type latch is designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

SN54LVC373A . . . J OR W PACKAGE SN74LVC373A . . . DB, DW, OR PW PACKAGE (TOP VIEW)



SN54LVC373A . . . FK PACKAGE (TOP VIEW)



While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54LVC373A is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74LVC373A is characterized for operation from –40°C to 85°C.



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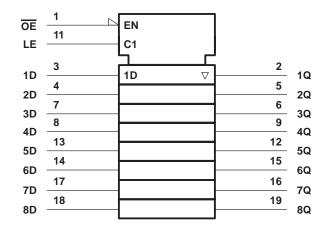
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### FUNCTION TABLE (each latch)

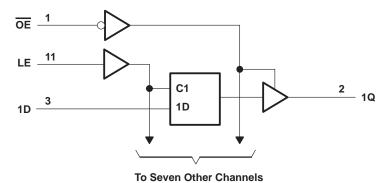
	INPUTS	ОИТРИТ	
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q <sub>0</sub>
Н	X	Χ	Z

### logic symbol†



<sup>&</sup>lt;sup>†</sup>This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V (co. Note 1)	
Input voltage range, V <sub>I</sub> (see Note 1)	–0.5 V 10 6.5 V
Voltage range applied to any output in the high-impedance or power-off state, VO	
(see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	–0.5 V to $V_{CC}$ + 0.5 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Continuous output current, IO	±50 mA
Continuous current through V <sub>CC</sub> or GND	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 3): DB package	115°C/W
DW package	97°C/W
PW package	128°C/W
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
  - 3. The package thermal impedance is calculated in accordance with JESD 51.

#### recommended operating conditions (see Note 4)

			SN54LVC373A		SN74L	VC373A		
			MIN	MAX	MIN	MAX	UNIT	
V	Cumphyyaltaga	Operating	2	3.6	1.65	3.6	V	
VCC	Supply voltage	Data retention only	1.5		1.5		V	
		V <sub>CC</sub> = 1.65 V to 1.95 V			0.65 × V <sub>CC</sub>			
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$			1.7		V	
		V <sub>CC</sub> = 2.7 V to 3.6 V	2		2			
		V <sub>CC</sub> = 1.65 V to 1.95 V				0.35 × V <sub>CC</sub>		
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V				0.7	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V		0.8		0.8	1	
٧ <sub>I</sub>	Input voltage		0	5.5	0	5.5	V	
	Output walks as	High or low state	0	Vcc	0	Vcc	V	
۷O	Output voltage	3 state	0	5.5	0	5.5	V	
		V <sub>CC</sub> = 1.65 V				-4		
la	High-level output current	V <sub>CC</sub> = 2.3 V				-8	mA	
IOH	riigii-ievei output current	V <sub>CC</sub> = 2.7 V		-12		-12	IIIA	
		V <sub>CC</sub> = 3 V		-24		-24		
		V <sub>CC</sub> = 1.65 V				4		
la.	Low lovel output ourrent	V <sub>CC</sub> = 2.3 V				8		
lOL	Low-level output current	V <sub>CC</sub> = 2.7 V		12		12	mA	
		VCC = 3 V		24		24		
Δt/Δν	Input transition rise or fall rate		0	10	0	10	ns/V	
TA	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



### SN54LVC373A, SN74LVC373A OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

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## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDIT	IONE	T	SN54	LVC373	Ą	SN74	LVC373	A	UNIT	
PARAMETER	TEST CONDIT	IONS	Vcc	MIN	TYP†	MAX	MIN	TYP†	MAX	UNII	
	100 00		1.65 V to 3.6 V				V <sub>CC</sub> -0.2				
Voн	ΙΟΗ = -100 μΑ		2.7 V to 3.6 V	V <sub>CC</sub> -0.2							
	I <sub>OH</sub> = -4 mA		1.65 V				1.2				
	I <sub>OH</sub> = -8 mA		2.3 V				1.7			V	
	I <sub>OH</sub> = -12 mA		2.7 V	2.2			2.2				
	IOH = -12 IIIA		3 V	2.4			2.4				
	I <sub>OH</sub> = -24 mA		3 V	2.2			2.2				
VoL	la 100 A		1.65 V to 3.6 V						0.2		
	I <sub>OL</sub> = 100 μA		2.7 V to 3.6 V			0.2					
	I <sub>OL</sub> = 4 mA		1.65 V						0.45	V	
	I <sub>OL</sub> = 8 mA		2.3 V						0.7	V	
	I <sub>OL</sub> = 12 mA		2.7 V			0.4			0.4		
	I <sub>OL</sub> = 24 mA		3 V			0.55			0.55		
lį	V <sub>I</sub> = 0 to 5.5 V		3.6 V			±5			±5	μΑ	
l <sub>off</sub>	$V_I$ or $V_O = 5.5 V$		0						±10	μА	
loz	$V_0 = 0 \text{ to } 5.5 \text{ V}$		3.6 V			±15			±10	μΑ	
	V <sub>I</sub> = V <sub>CC</sub> or GND		0.01/			10			10		
Icc	$3.6 \text{ V} \le \text{V}_{\text{I}} \le 5.5 \text{ V}^{\ddagger}$	IO = 0	3.6 V			10			10	μΑ	
ΔICC	One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND		2.7 V to 3.6 V			500			500	μΑ	
C <sub>i</sub>	$V_I = V_{CC}$ or GND		3.3 V		4	12		4		pF	
Co	$V_O = V_{CC}$ or GND		3.3 V		5.5	12		5.5		pF	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

# timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

			SN54LVC373A				
		V <sub>CC</sub> = 2.7 V		$V_{CC}$ = 3.3 V $\pm$ 0.3 V		UNIT	
		MIN	MAX	MIN	MAX		
t <sub>W</sub>	Pulse duration, LE high	3.3		3.3		ns	
t <sub>su</sub>	Setup time, data before LE↓	2		2		ns	
th	Hold time, data after LE↓	2		2		ns	

<sup>&</sup>lt;sup>‡</sup> This applies in the disabled state only.

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## timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

		SN74LVC373A								
		V <sub>CC</sub> =	1.8 V 5 V	V <sub>CC</sub> =	2.5 V 2 V	V <sub>CC</sub> =	2.7 V	V <sub>CC</sub> =	3.3 V 3 V	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>W</sub>	Pulse duration, LE high	†		†		3.3		3.3		ns
t <sub>su</sub>	Setup time, data before LE↓	†		†		2		2		ns
t <sub>h</sub>	Hold time, data after LE↓	†		†		1.5		1.5		ns

<sup>†</sup> This information was not available at the time of publication.

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

	SN54LV						
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 2.7 V	V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT	
					MAX		
+ .	D	Q	8.5	1	7.5	nc	
t <sub>pd</sub>	LE	y	8.5 1 7.5 9.5 1 8.5	115			
t <sub>en</sub>	ŌĒ	Q	8.7	1	7.7	ns	
<sup>t</sup> dis	ŌĒ	Q	8	0.5	7	ns	

## switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

		TO (OUTPUT)	SN74LVC373A								
PARAMETER	FROM (INPUT)		V <sub>CC</sub> =		V <sub>CC</sub> =	2.5 V 2 V	V <sub>CC</sub> =	2.7 V	V <sub>CC</sub> =	3.3 V 3 V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	D	Q	†	†	†	†		7.8	1.5	6.8	ns
<sup>t</sup> pd	LE		†	†	†	†		8.2	2	7.6	110
t <sub>en</sub>	ŌE	Q	†	†	†	†		8.7	1.5	7.7	ns
tdis	ŌE	Q	†	†	†	†		7.6	1.5	7	ns
t <sub>sk(o)</sub> ‡										1	ns

<sup>&</sup>lt;sup>†</sup> This information was not available at the time of publication.

### operating characteristics, T<sub>A</sub> = 25°C

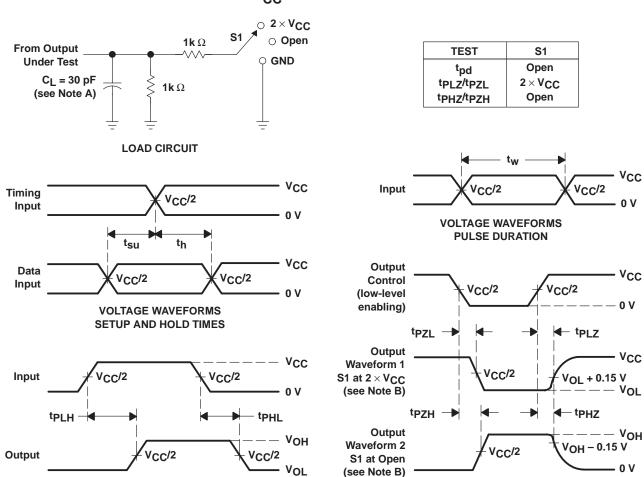
PARAMETER			TEST CONDITIONS	V <sub>CC</sub> = 1.8 V ± 0.15 V	V <sub>CC</sub> = 2.5 V ± 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V	UNIT
		CONDITIONS	TYP	TYP	TYP		
C <sub>pd</sub>	Power dissipation capacitance	Outputs enabled	f = 10 MHz	†	†	46	pF
Сра	per latch	Outputs disabled	T = TO WIHZ	†	†	3	pr

<sup>†</sup>This information was not available at the time of publication.



<sup>‡</sup> Skew between any two outputs of the same package switching in the same direction

### PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

**VOLTAGE WAVEFORMS** 

**ENABLE AND DISABLE TIMES** 

- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq$  2 ns.  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.

**VOLTAGE WAVEFORMS** 

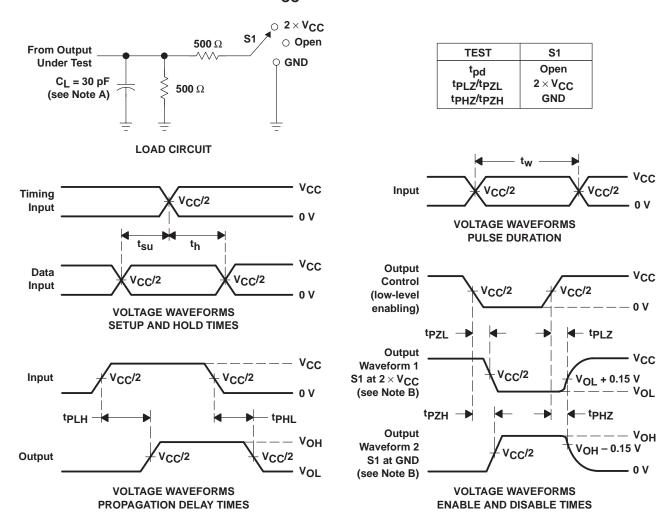
**PROPAGATION DELAY TIMES** 

- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



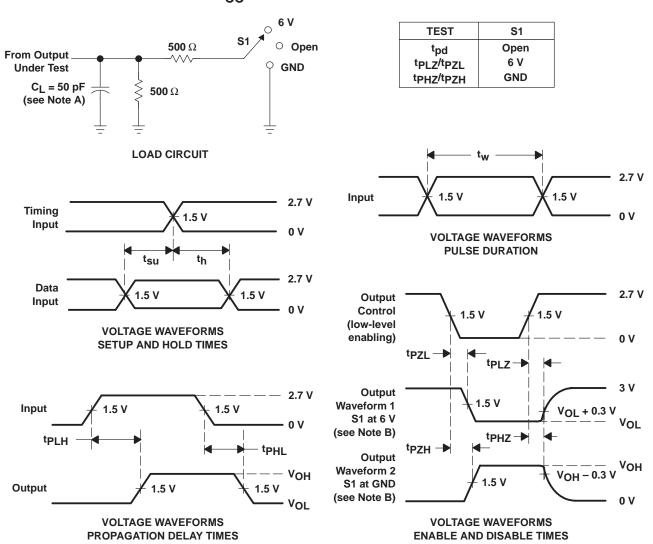
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ ,  $t_f \leq$  2 ns,  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms

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## PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2.5 ns.  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms



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